

Description

The IRF740 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gat e charge. It can be used in a wide variety of applications.

G S

TO-220 (TO-220AB)

General Features

V_{DS} =420V,I_D =11A

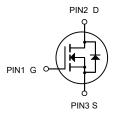
 $R_{DS(ON)} < 0.5 \Omega$ @ $V_{GS} = 10V$

Application

High efficiency switch mode power supplies

Power factor correction

Electronic lamp ballast



N-Channel MOSFET

Package Marking and Ordering Information

| Product ID | Pack | Marking | Units Tube |
|------------|------------------|-------------|------------|
| IRF740 | TO-220(TO-220AB) | IRF740 XXXX | 50 |

Absolute Maximum Ratings@T_j=25°C(unless otherwise specified)

| Symbol | Parameter | Rating | Units |
|--------------------------------------|---------------------------------------|-------------|-------|
| VDS | Drain-Source Voltage | 420 | V |
| VGS | Gate-Source Voltage | <u>+</u> 30 | V |
| I _D @T _C =25°C | Drain Current, V _{GS} @ 4.5V | 11 | Α |
| IDM | Pulsed Drain Current ¹ | 44 | Α |
| P _D @T _C =25°C | Total Power Dissipation | 87 | W |
| TSTG | Storage Temperature Range | -55 to 150 | °C |
| TJ | Operating Junction Temperature Range | -55 to 150 | °C |



Electrica Characteristics (T_C=25°C, unless otherwise specified)

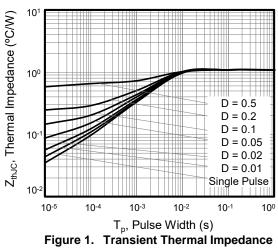
| | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | LIMIT |
|---|----------------------------------|--|--|--|--|---|
| - | | 1 | 101111 | 1 11 | IVIAA | CIVII |
| | | | | | | |
| OFF CHARACTERISTICS Drain-Source Breakdown Voltage | | V_{GS} =0V, I_D =250 μ A | 420 | | | V |
| Drain-Source Leakage Current | | V _{DS} =650V, V _{GS} =0V | | | 1 | μΑ |
| Gate- Source Leakage Current Reverse | | V _{G=} 30V, V _{DS} =0V | | | 100 -100 | nA nA |
| , | | 100 001, 150 01 | | | | |
| | $V_{GS(TH)}$ | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 2.0 | | | V |
| Static Drain-Source On-State Resistance | | V_{GS} =10V, I_{D} =1A | | 0.36 | 0.5 | Ω |
| | | | | | | |
| nput Capacitance Output Capacitance | | | | 1368 | | pF |
| | | V _{DS} =25V, V _{GS} =0V, f=1.0 MHz | | 90.3 | | рF |
| Reverse Transfer Capacitance | | 1 | | 3 | | рF |
| 3 | | | | | | |
| | t _{D(ON)} | | | 16 | | ns |
| Turn-On Delay Time Turn-On Rise Time | | ' - ' | | 25 | | ns |
| Turn-Off Delay Time | | $R_G = 25\Omega$ (Note 1, 2) | | 40 | | ns |
| | t _F | 1 | | 29 | | ns |
| Turn-Off Fall Time Total Gate Charge Gate-Source Charge Gate-Drain Charge | | V -490V I -12A | | 8.1 | | nC |
| | | | | 7.4 | | nC |
| | | VGS=10V (Note 1, 2) | | 5 | | nC |
| CTERISTIC | S AND MAXI | MUM RATINGS | • | | | |
| Drain-Source Diode Forward Voltage | | V _{GS} = 0 V, I _S = 11A | | | 1.2 | V |
| Maximum Continuous Drain-Source Diode | | | | | 11 | Α |
| Forward Current | | | | | 11 | ^ |
| Maximum Pulsed Drain-Source Diode Forward Current | | | | | 44 | Α |
| | ·SIVI | | | | | |
| | t _{rr} | | | 435 | | ns |
| Reverse Recovery Charge | | dI _F /dt =100 A/μs (Note 1) | | 4 | | μC |
| | stance CTERISTIC ge e Diode ode | VGS(TH) Stance VGS(TH) Stance RDS(ON) | $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$ | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ |

Notes: 1. Pulse Test: Pulse width ≤ 300µs, Duty cycle ≤ 2%.

^{2.} Essentially independent of operating temperature.



Typical Characteristics:



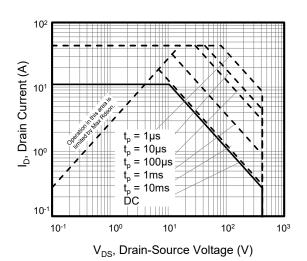


Figure 2. Safe Operation Area

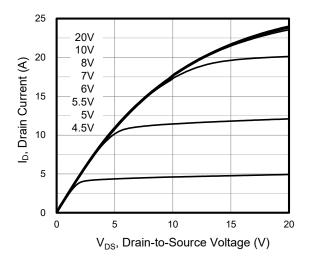


Figure 3. Output Characteristics

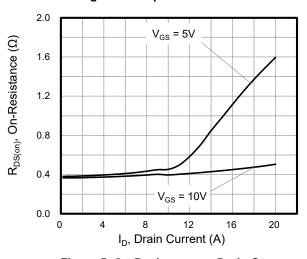


Figure 5. On-Resistance vs Drain Current

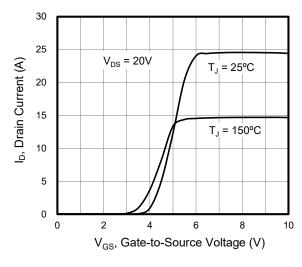


Figure 4. Transfer Characteristics

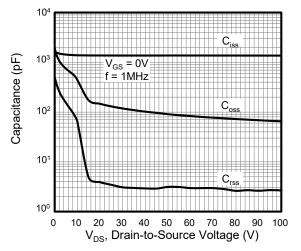
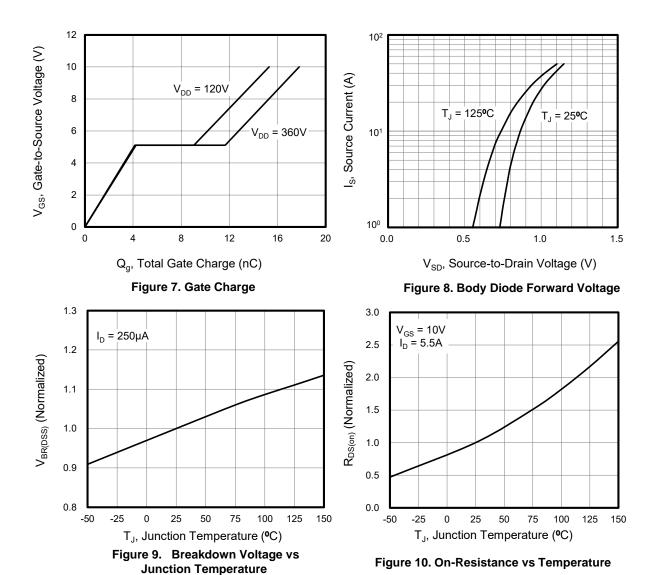
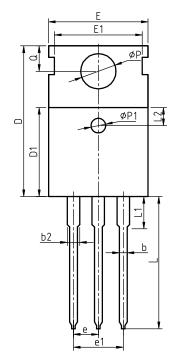


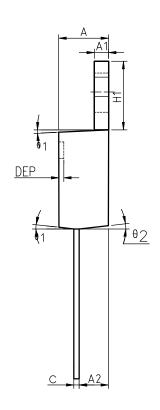
Figure 6. Capacitance





Package Information TO-220(TO-220AB)





COMMON DIMENSIONS



| SYMBOL | MIN | NOM | MAX | MIN | NOM | MAX |
|--------|-------|-------|-------|--------|-------|-------|
| Α | 4.40 | 4.57 | 4.70 | 0.173 | 0.180 | 0.185 |
| A1 | 1. 27 | 1.30 | 1.33 | 0.050 | 0.051 | 0.052 |
| A2 | 2. 35 | 2.40 | 2.50 | 0.093 | 0.094 | 0.098 |
| b | 0.77 | 0.80 | 0.90 | 0.030 | 0.031 | 0.035 |
| b2 | 1. 17 | 1. 27 | 1.36 | 0.046 | 0.050 | 0.054 |
| С | 0.48 | 0.50 | 0.56 | 0.019 | 0.020 | 0.022 |
| D | 15.40 | 15.60 | 15.80 | 0.606 | 0.614 | 0.622 |
| D1 | 9.00 | 9. 10 | 9.20 | 0.354 | 0.358 | 0.362 |
| DEP | 0.05 | 0.10 | 0.20 | 0.002 | 0.004 | 0.008 |
| E | 9.80 | 10.00 | 10.20 | 0.386 | 0.394 | 0.402 |
| E1 | ı | 8.70 | ı | - | 0.343 | - |
| E2 | 9.80 | 10.00 | 10.20 | 0.386 | 0.394 | 0.402 |
| е | | 2.54 | BSC | | 0.100 | BSC |
| e1 | | 5.08 | BSC | | 0.200 | BSC |
| H1 | 6.40 | 6.50 | 6.60 | 0. 252 | 0.256 | 0.260 |
| L | 12.75 | 13.50 | 13.65 | 0.502 | 0.531 | 0.537 |
| L1 | - | 3.10 | 3.30 | - | 0.122 | 0.130 |
| L2 | | 2.50 | REF | | 0.098 | REF |
| Р | 3.50 | 3.60 | 3.63 | 0.138 | 0.142 | 0.143 |
| P1 | 3.50 | 3.60 | 3.63 | 0.138 | 0.142 | 0.143 |
| Q | 2.73 | 2.80 | 2.87 | 0.107 | 0.110 | 0.113 |
| θ 1 | 5° | 7° | 9° | 5° | 7° | 9° |
| θ 2 | 1° | 3° | 5° | 1° | 3° | 5° |
| θ 3 | 1° | 3° | 5° | 1° | 3° | 5° |



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